

# isc N-Channel MOSFET Transistor

## STB28NM50N

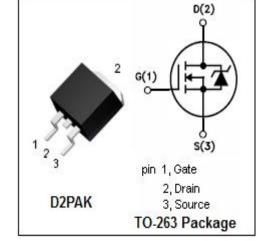
### • FEATURES

- With TO-263( D2PAK ) packaging
- · High speed switching
- · Low gate input resistance
- · Standard level gate drive
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



### APPLICATIONS

- Power supply
- · Switching applications

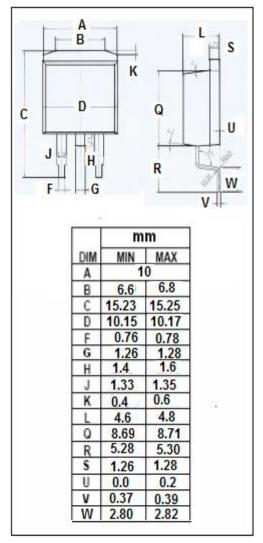


### • ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	500	V
V <sub>GSS</sub>	Gate-Source Voltage	±25	V
I <sub>D</sub>	Drain Current-Continuous@ $T_c$ =25° $C$ $T_c$ =100° $C$	21 13	А
I <sub>DM</sub>	Drain Current-Single Pulsed	84	A
P <sub>D</sub>	Total Dissipation	150	W
Tj	Operating Junction Temperature 150		${\mathbb C}$
T <sub>stg</sub>	Storage Temperature -55~1		$^{\circ}$ C



SYMBOL	PARAMETER		UNIT		
Rth(ch-c)	Channel-to-case thermal resistance	0.83	°C/W		
Rth(ch-a)	Channel-to-ambient thermal resistance	62.5	°C/W		





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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 1mA	500			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =±25V; I <sub>D</sub> =0.25mA	2.0		4.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =10.5A		135	158	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±25V;V <sub>DS</sub> = 0V			±0.1	μ <b> A</b>
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 500V; V <sub>GS</sub> = 0V;Tj=25℃ Tj=125℃			1 100	μ <b>А</b>
$V_{SDF}$	Diode forward voltage	I <sub>SD</sub> =21A, V <sub>GS</sub> = 0 V			1.5	V



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